











TL2842, TL2843, TL2844, TL2845 TL3842, TL3843, TL3844, TL3845

SLVS038H - JANUARY 1989-REVISED JANUARY 2015

TLx84x Current-Mode PWM Controllers

Features

- Optimized for Off-Line and DC-to-DC Converters
- Low Start-Up Current (< 1 mA)
- Automatic Feed-forward compensation
- Pulse-by-Pulse Current Limiting
- **Enhanced Load-Response Characteristics**
- Undervoltage Lockout With Hysteresis
- **Double-Pulse Suppression**
- High-Current Totem-Pole Output
- Internally Trimmed Bandgap Reference
- 500-kHz Operation
- Error Amplifier With Low Output Resistance
- Designed to be Interchangeable with UC2842 and UC3842 Series

2 Applications

- Switching regulators of any polarity
- Transformer-coupled DC/DC convertors

3 Description

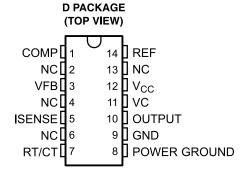
The TL284x and TL384x series of control integrated circuits provide the features that are necessary to implement off-line or DC-to-DC fixed-frequency current-mode control schemes, with a minimum number of external components. Some of the internally implemented circuits are an undervoltage lockout (UVLO), featuring a start-up current of less than 1 mA, and a precision reference trimmed for accuracy at the error amplifier input. Other internal circuits include logic to ensure latched operation, a pulse-width modulation (PWM) comparator (that also provides current-limit control), and a totem-pole output stage designed to source or sink high-peak current. The output stage, suitable for driving Nchannel MOSFETs, is low when it is in the off state.

Device Information⁽¹⁾

PART NUMBER	PACKAGE (PIN)	BODY SIZE (NOM)		
	SOIC (8)	4.90 mm × 3.91 mm		
TLx84x	SOIC (14)	8.65 mm × 3.91 mm		
	PDIP (8)	9.81 mm × 6.35 mm		

(1) For all available packages, see the orderable addendum at the end of the datasheet.

4 Device Pinout Drawing



NC - No internal connection

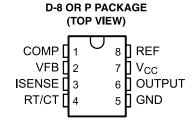






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5 Revision History

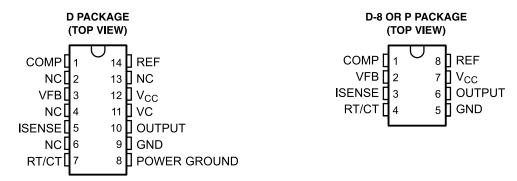
Changes from Revision G (February 2008) to Revision H

Page

Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table,
 Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation
 section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and
 Mechanical, Packaging, and Orderable Information section.
 Deleted Ordering Information table.



6 Pin Configuration and Functions



NC - No internal connection

Pin Functions

	T III T GIOGOTO										
	PIN		TVDE	DESCRIPTION							
NAME	D	D-8 or P	TYPE	DESCRIPTION							
COMP	1	1	I/O	Error amplifier compensation pin							
GND	9	5	_	Device power supply ground terminal							
ISENSE	5	3	I	Current sense comparator input							
NC	2, 4, 6, 13	-	_	Do not connect							
OUTPUT	10	6	0	PWM Output							
POWER GROUND	8	-	_	Output PWM ground terminal							
REF	14	8	0	Oscillator voltage reference							
RT/CT	7	4	I/O	Oscillator RC input							
VC	11	-	_	Output PWM positive voltage supply							
V _{CC}	12	7	_	Device positive voltage supply							
VFB	3	2	I	Error amplifier input							



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN MA	X UNIT
V _{CC}	Supply Voltage (2)	Self limiting	_
VI	Analog input voltage range, VFB and ISENSE	-0.3 6.	3 V
Vo	Output Voltage	3	5 V
VI	Input Voltage, VC and D Package only	3	5 V
I _{CC}	Supply current	3	0 mA
Io	Output current	±	1 A
	error amplifier output sink current	1	0 mA
T_{J}	Virtual junction temperature	15	O °C
	Output energy (capacitive load)		5 μJ
T _{stg}	Storage temperature range	-65 15	0 °C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
V	Clastrostatia dia shares	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	3000	V
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	3000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	TYP	MAX	UNIT
V _{CC} and VC ⁽¹⁾	Supply Voltage				30	V
V _I , RT/CT	Input Voltage		0		5.5	V
V _I , VFB and ISENSE	Input Voltage		0		5.5	V
V _O , OUTPUT	Output voltage		0		30	V
V _O , POWER GROUND ⁽¹⁾	Output voltage		-0.1		1	V
Icc	Supply current, externally limited				25	mA
Io	Average output current				200	mA
I _{O(ref)}	Reference output current				-20	mA
f _{OSC}	Oscillator frequency	Oscillator frequency				kHz
т	Operating free air temperature	TL284x	-40		85	°C
T_A	Operating free-air temperature	TL984x	0		70	30

⁽¹⁾ These recommended voltages for VC and POWER GROUND apply only to the D package.

7.4 Thermal Information

		TLx84x						
	THERMAL METRIC ⁽¹⁾	D	D P		UNIT			
		8 PINS	14 PINS	8 PINS				
$R_{\theta JA}$	Junction-to-ambient thermal resistance	97	86	85	°C/W			

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

⁽²⁾ All voltages are with respect to the device GND pin.

²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.5 Electrical Characteristics

over operating free-air temperature range, V_{CC} = 15 $V^{(1)}$, R_T = 10 $k\Omega$, C_T = 3.3 nF (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽²⁾		TL284x			TL384x		UNIT
PARAMETER		TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	MIN	TYP ⁽²⁾	MAX	UNII
Reference Section									
Output voltage		$I_{O} = 1 \text{ mA}, T_{A} = 25^{\circ}\text{C}$	4.95	5	5.05	4.9	5	5.1	V
Line regulation		V _{CC} = 12 V to 25 V		6	20		6	20	mV
Load regulation		$I_O = 1 \text{ mA to } 20 \text{ mA}$		6	25		6	25	mV
Temperature coefficient of out	put voltage			0.2	0.4		0.2	0.4	mV/°C
Output voltage with worst-case	e variation	V_{CC} = 12 V to 25 V, I_{O} = 1 mA to 20 mA	4.9		5.1	4.82		5.18	٧
Output noise voltage		f = 10 Hz to 10 kHz, T _A = 25°C		50			50		μV
Output-voltage long-term drift		After 1000 h at T _A = 25°C		5	25		5	25	mV
Short-circuit output current		-30	-100	-180	-30	-100	-180	mA	
Oscillator Section									
Oscillator frequency (3)		T _A = 25°C	47	52	57	47	52	57	kHz
Frequency change with supply	voltage	V _{CC} = 12 V to 25 V		2	10		2	10	Hz/kHz
Frequency change with temper	rature			50			50		Hz/kHz
peak-to-peak amplitude at RT	CT			1.7			1.7		V
Error-Amplifier Section									
Feedback input voltage		COMP at 2.5 V	2.45	2.50	2.55	2.42	2.50	2.58	V
Input bias current				-0.3	-1		-0.3	-2	μΑ
Open-loop voltage amplification	n	V _O = 2 V to 4 V	65	90		65	90		dB
Gain-bandwidth product			0.7	1		0.7	1		MHz
Supply-voltage rejection ratio		V _{CC} = 12 V to 25 V	60	70		60	70		dB
Output sink current		VFB, at 2.7 V, COMP at 1.1 V	2	6		2	6		mA
Output source current		VFB, at 2.3 V, COMP at 5 V	-0.5	-0.8		-0.5	-0.8		mA
Hihg-level output voltage		VFB, at 2.3 V, $R_L = 15 \text{ k}\Omega$ to GND	5	6		5	6		V
Low-level output voltage		VFB, at 2.7 V, $R_L = 15 \text{ k}\Omega$ to GND		0.7	1.1		0.7	1.1	V
Current-sense Section		•			•				
Voltage amplification		See ⁽⁴⁾⁽⁵⁾	2.85	3	3.13	2.85	3	3.15	V/V
Current-sense comparator three	eshold	COMP at 5 V, see ⁽⁴⁾	0.9	1	1.1	0.9	1	1.1	V
Supply-voltage rejection ratio		V _{CC} = 12 V to 25 V, see ⁽⁴⁾		70			70		dB
Input bias current				-2	-10		-2	-10	μA
Delay time to output				150	300		150	300	ns
Output Section		1							
		$I_{OH} = -20 \text{ mA}$	13	13.5		13	13.5		
High-level output voltage		I _{OH} = -200 mA	12	13.5		13	13.5		V
		I _{OH} = 20 mA		0.1	0.4		0.1	0.4	.,
Low-level output voltage	I _{OH} = 200 mA		1.5	2.2		1.5	2.2	V	
Rise time	C _L = 1 nF, T _A = 25°C		50	150		50	150	ns	
fall time		C _L = 1 nF, T _A = 25°C		50	150		50	150	ns
Undervoltage-Lockout Section		<u> </u>							
	TLx842, TLx844		15	16	17	14.5	16	17.5	
Start threshold voltage	TLx843, TLx845	7	7.8	8.4	9	7.8	8.4	9	V

⁽¹⁾ Adjust V_{CC} above the start threshold before setting it to 15 V. (2) All typical values are at TA = 25°C.

Output frequency equals oscillator frequency for the TLx842 and TLx843. Output frequency is one-half the oscillator frequency for the TLx844 and TLx845.

These parameters are measured at the trip point of the latch, with VFB at 0 V.

Voltage amplification is measured between ISENSE and COMP, with the input changing from 0 V to 0.8 V.

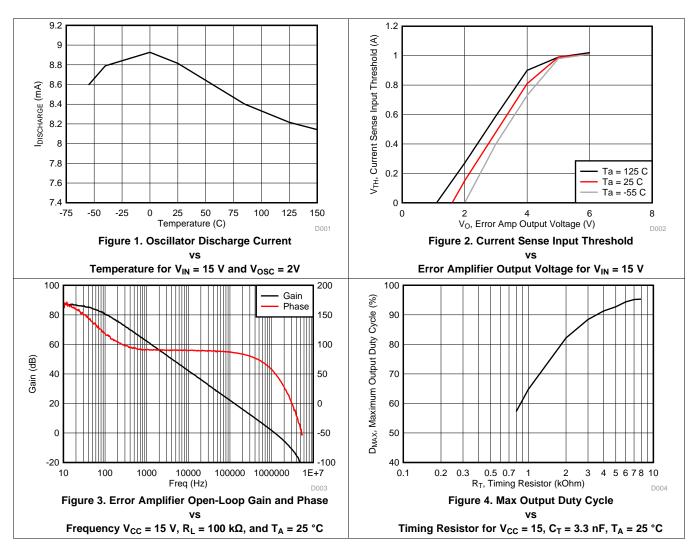


Electrical Characteristics (continued)

over operating free-air temperature range, V_{CC} = 15 $V^{(1)}$, R_T = 10 $k\Omega$, C_T = 3.3 nF (unless otherwise noted)

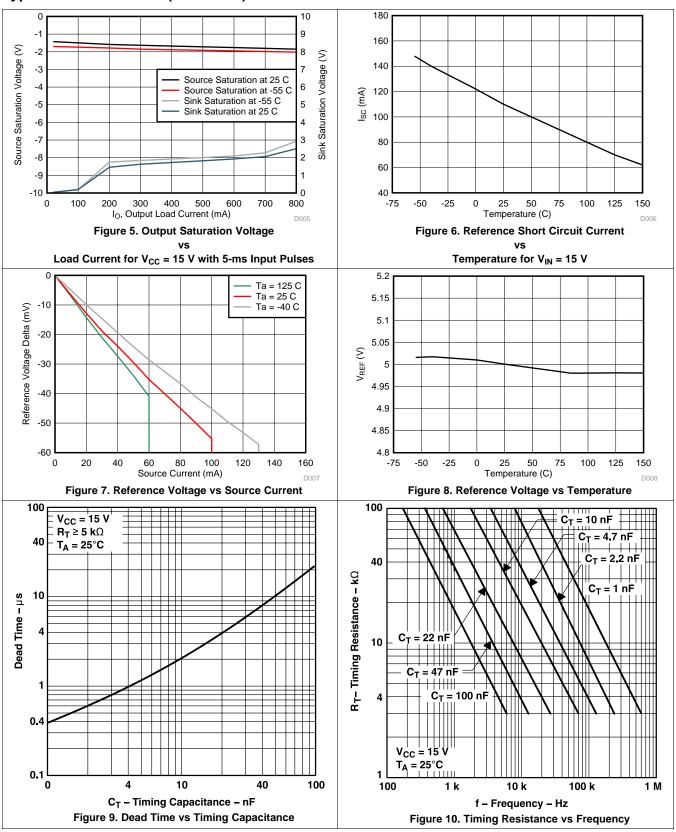
DADAMETER		TEST CONDITIONS ⁽²⁾		TL284x			TL384x		UNIT	
PARAMETER		1EST CONDITIONS	MIN	TYP ⁽²⁾	MAX	MIN	TYP ⁽²⁾	MAX	UNIT	
Minimum operating voltage	TLx842, TLx844		9	10	11	8.5	10	11.5	V	
after startup	TLx843, TLx845		7	7.6	8.2	7	7.6	8.02	V	
Pulse-Width-Modulator Section										
Maximum duty cycle	TLx842, TLx844		95	97	100	95	97	100		
Maximum duty cycle	TLx843, TLx845		46	48	50	46	48	50	%	
Minimum duty cycle					0			0		
Supply Voltage										
Start-up current				0.5	1		0.5	1	mA	
Operating supply current		VFB and ISENSE at 0 V		11	17		11	17	mA	
Limiting voltage	·	I _{CC} = 25 mA		34			34		V	

7.6 Typical Characteristics





Typical Characteristics (continued)



8 Detailed Description

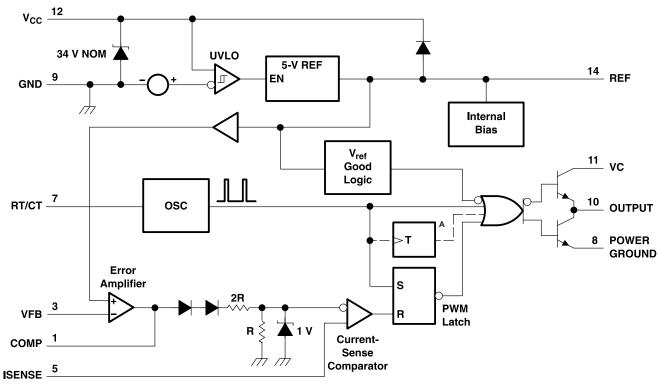
8.1 Overview

The TL284x and TL384x series of control integrated circuits provide the features that are necessary to implement off-line or DC-to-DC fixed-frequency current-mode control schemes, with a minimum number of external components. Some of the internally implemented circuits are an undervoltage lockout (UVLO), featuring a start-up current of less than 1 mA, and a precision reference trimmed for accuracy at the error amplifier input. Other internal circuits include logic to ensure latched operation, a pulse-width modulation (PWM) comparator (that also provides current-limit control), and a totem-pole output stage designed to source or sink high-peak current. The output stage, suitable for driving N-channel MOSFETs, is low when it is in the off state.

Major differences between members of these series are the UVLO thresholds and maximum duty-cycle ranges. Typical UVLO thresholds of 16 V (on) and 10 V (off) on the TLx842 and TLx844 devices make them ideally suited to off-line applications. The corresponding typical thresholds for the TLx843 and TLx845 devices are 8.4 V (on) and 7.6 V (off). The TLx842 and TLx843 devices can operate to duty cycles approaching 100%. A duty-cycle range of 0 to 50% is obtained by the TLx844 and TLx845 by the addition of an internal toggle flip-flop, which blanks the output off every other clock cycle.

The TL284x-series devices are characterized for operation from -40° C to 85°C. The TL384x devices are characterized for operation from 0°C to 70°C.

8.2 Functional Block Diagram



A. The toggle flip-flop is present only in TL2844, TL2845, TL3844, and TL3845. Pin numbers shown are for the D (14-pin) package.

8.3 Feature Description

8.3.1 Pulse-by-Pulse Current Limiting

Pulse-by-pulse limiting is inherent in the control scheme. An upper limit on the peak current can be established by simply clamping the error voltage. Accurate current limiting allows optimization of magnetic and power semiconductor elements while ensuring reliable supply operation



Feature Description (continued)

8.3.2 Error Amplifier With Low Output Resistance

With a low output resistance, various impedance networks may be used on the compensation pin input for error amplifier feedback.

8.3.3 High-Current Totem-Pole Output

The output of the TLx84x devices can sink or source up to 1 A of current.

8.4 Device Functional Modes

8.4.1 Shutdown Technique

The PWM controller (see Figure 11) can be shut down by two methods: either raise the voltage at ISENSE above 1 V or pull the COMP terminal below a voltage two diode drops above ground. Either method causes the output of the PWM comparator to be high (refer to block diagram). The PWM latch is reset dominant so that the output remains low until the next clock cycle after the shutdown condition at the COMP or ISENSE terminal is removed. In one example, an externally latched shutdown can be accomplished by adding an SCR that resets by cycling VCC below the lower UVLO threshold. At this point, the reference turns off, allowing the SCR to reset.

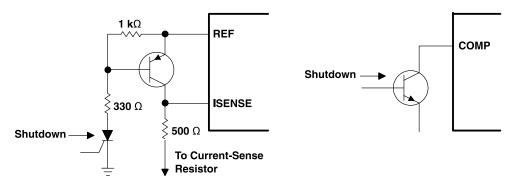


Figure 11. Shutdown Techniques

8.4.2 Slope Compensation

A fraction of the oscillator ramp can be summed resistively with the current-sense signal to provide slope compensation for converters requiring duty cycles over 50% (see Figure 12). Note that capacitor C forms a filter with R2 to suppress the leading-edge switch spikes.

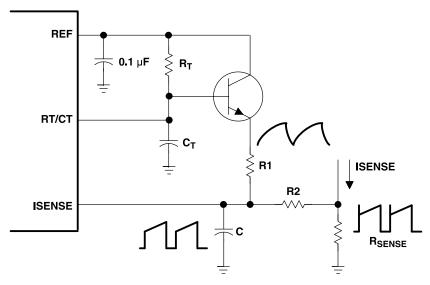


Figure 12. Slope Compensation

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Typical Application

The following application is an open-loop laboratory test fixture. This circuit demonstrates the setup and use of the TL284x and TL384x devices and their internal circuitry.

In the open-loop laboratory test fixture (see Figure 13), high peak currents associated with loads necessitate careful grounding techniques. Timing and bypass capacitors should be connected close to the GND terminal in a single-point ground. The transistor and 5-k Ω potentiometer sample the oscillator waveform and apply an adjustable ramp to the ISENSE terminal.

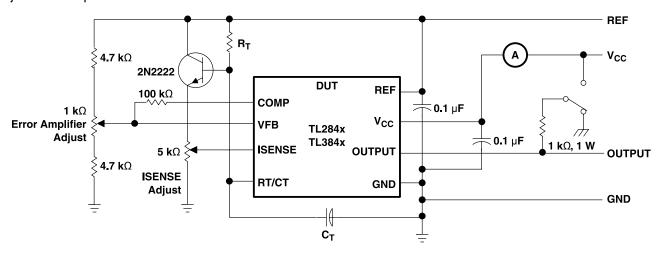


Figure 13. Open-Loop Laboratory Test Fixture

9.1.1 Design Requirements

The design techniques in the following sections may be used for power supply PWM applications which fall within the following requirements.

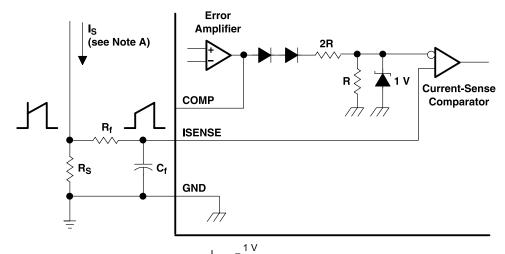
- 500-kHz or lower operation
- 30-V or less output voltage
- 200-mA or less output current



Typical Application (continued)

9.1.2 Detailed Design Procedure

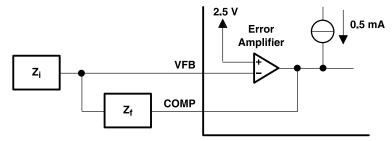
9.1.2.1 Current-Sense Circuit



A. Peak current (IS) is determined by the formula: $I_{s(max)} = \frac{1}{R_s} \times I_{s(max)} = \frac{1}{$

Figure 14. Current-Sense Circuit Schematic

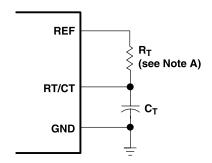
9.1.2.2 Error-Amplifier Configuration



A. Error amplifier can source or sink up to 0.5 mA.

Figure 15. Error-Amplifier Configuration Schematic

9.1.2.3 Oscillator Section



 $A. \quad \text{ For } R_T > 5 \text{ k}\Omega; \\ f \approx \frac{1.72}{R_{_T}C_{_T}}$

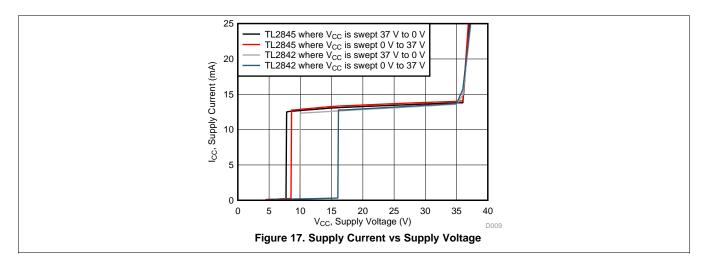
Figure 16. Oscillator Section Schematic



Typical Application (continued)

9.1.3 Application Curves

Application curves show oscillator characteristics for chosen capacitor and resistor values.



10 Power Supply Recommendations

See *Recommended Operating Conditions* for the recommended power supply voltages for the TL284x and TL384x devices. It is also recommended to have a decoupling capacitor on the output of the device's power supply to limit noise on the device input.



11 Layout

11.1 Layout Guidelines

Always try to use a low EMI inductor with a ferrite type closed core. Some examples would be toroid and encased E core inductors. Open core can be used if they have low EMI characteristics and are located a bit more away from the low power traces and components. Make the poles perpendicular to the PCB as well if using an open core. Stick cores usually emit the most unwanted noise.

11.1.1 Feedback Traces

Try to run the feedback trace as far from the inductor and noisy power traces as possible. You would also like the feedback trace to be as direct as possible and somewhat thick. These two sometimes involve a trade-off, but keeping it away from inductor EMI and other noise sources is the more critical of the two. Run the feedback trace on the side of the PCB opposite of the inductor with a ground plane separating the two.

11.1.2 Input/Output Capacitors

When using a low value ceramic input filter capacitor, it should be located as close to the VCC pin of the IC as possible. This will eliminate as much trace inductance effects as possible and give the internal IC rail a cleaner voltage supply. Some designs require the use of a feed-forward capacitor connected from the output to the feedback pin as well, usually for stability reasons. In this case it should also be positioned as close to the IC as possible. Using surface mount capacitors also reduces lead length and lessens the chance of noise coupling into the effective antenna created by through-hole components.

11.1.3 Compensation Components

External compensation components for stability should also be placed close to the IC. Surface mount components are recommended here as well for the same reasons discussed for the filter capacitors. These should not be located very close to the inductor either.

11.1.4 Traces and Ground Planes

Make all of the power (high current) traces as short, direct, and thick as possible. It is good practice on a standard PCB board to make the traces an absolute minimum of 15 mils (0.381 mm) per Ampere. The inductor, output capacitors, and output diode should be as close to each other possible. This helps reduce the EMI radiated by the power traces due to the high switching currents through them. This will also reduce lead inductance and resistance as well, which in turn reduces noise spikes, ringing, and resistive losses that produce voltage errors.

The grounds of the IC, input capacitors, output capacitors, and output diode (if applicable) should be connected close together directly to a ground plane. It would also be a good idea to have a ground plane on both sides of the PCB. This will reduce noise as well by reducing ground loop errors as well as by absorbing more of the EMI radiated by the inductor. For multi-layer boards with more than two layers, a ground plane can be used to separate the power plane (where the power traces and components are) and the signal plane (where the feedback and compensation and components are) for improved performance. On multi-layer boards the use of vias will be required to connect traces and different planes. It is good practice to use one standard via per 200 mA of current if the trace will need to conduct a significant amount of current from one plane to the other.

Arrange the components so that the switching current loops curl in the same direction. Due to the way switching regulators operate, there are two power states. One state when the switch is on and one when the switch is off. During each state there will be a current loop made by the power components that are currently conducting. Place the power components so that during each of the two states the current loop is conducting in the same direction. This prevents magnetic field reversal caused by the traces between the two half-cycles and reduces radiated EMI.



11.2 Layout Example

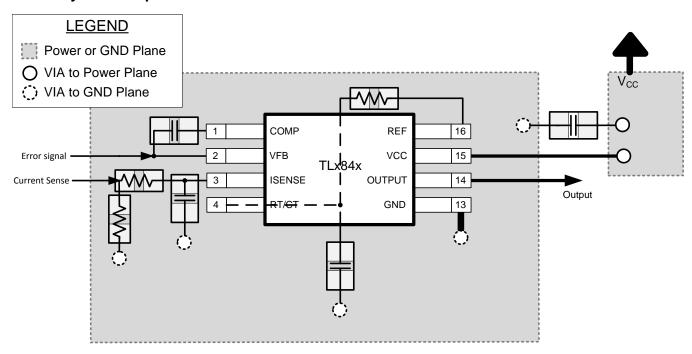


Figure 18. Layout of D-8 or P Package for TLx84x Devices



12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TL2842	Click here	Click here	Click here	Click here	Click here
TL2843	Click here	Click here	Click here	Click here	Click here
TL2844	Click here	Click here	Click here	Click here	Click here
TL2845	Click here	Click here	Click here	Click here	Click here
TL3842	Click here	Click here	Click here	Click here	Click here
TL3843	Click here	Click here	Click here	Click here	Click here
TL3844	Click here	Click here	Click here	Click here	Click here
TL3845	Click here	Click here	Click here	Click here	Click here

12.2 Trademarks

All trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





29-Oct-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)				-	(2)	(6)	(3)		(4/5)	
TL2842D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TL2842	Samples
TL2842D-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TL2842	Samples
TL2842DE4-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TL2842	Samples
TL2842DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TL2842	Samples
TL2842DR-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TL2842	Samples
TL2842P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TL2842P	Samples
TL2843D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2843	Samples
TL2843D-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2843	Samples
TL2843DG4-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2843	Samples
TL2843DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2843	Samples
TL2843DR-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2843	Samples
TL2843DRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2843	Samples
TL2843DRG4-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2843	Samples
TL2843P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TL2843P	Samples
TL2844D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2844	Samples
TL2844D-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2844	Samples
TL2844DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2844	Samples



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TL2844DR-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2844	Samples
TL2844DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2844	Samples
TL2844P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TL2844P	Samples
TL2844PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TL2844P	Samples
TL2845D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2845	Samples
TL2845D-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2845	Samples
TL2845DG4-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2845	Samples
TL2845DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2845	Samples
TL2845DR-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2845	Samples
TL2845DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL2845	Samples
TL2845P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TL2845P	Samples
TL2845PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TL2845P	Samples
TL3842D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	TL3842	Samples
TL3842D-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	TL3842	Samples
TL3842DE4-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	TL3842	Samples
TL3842DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	TL3842	Samples
TL3842DR-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	TL3842	Samples
TL3842DRE4-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	TL3842	Samples



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TL3842P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL3842P	Samples
TL3842PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL3842P	Samples
TL3843D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3843	Samples
TL3843D-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3843	Samples
TL3843DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3843	Samples
TL3843DR-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3843	Samples
TL3843DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3843	Samples
TL3843DRG4-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3843	Samples
TL3843P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL3843P	Samples
TL3843PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL3843P	Samples
TL3844D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3844	Samples
TL3844D-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3844	Samples
TL3844DG4-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3844	Samples
TL3844DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3844	Samples
TL3844DR-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3844	Samples
TL3844P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL3844P	Samples
TL3844PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL3844P	Samples
TL3845D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3845	Samples



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PACKAGE OPTION ADDENDUM

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Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TL3845D-8	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3845	Samples
TL3845DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3845	Samples
TL3845DR-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3845	Samples
TL3845DRE4-8	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3845	Samples
TL3845DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3845	Samples
TL3845P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL3845P	Samples
TL3845PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL3845P	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

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(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

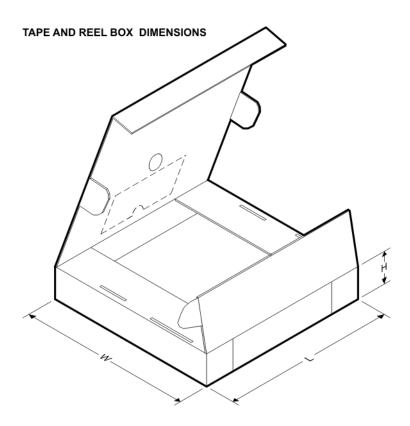


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL2842DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL2842DR-8	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL2843DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL2843DR-8	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL2844DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL2844DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL2844DR-8	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL2845DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL2845DR-8	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL3842DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL3842DR-8	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL3843DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL3843DR-8	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL3844DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL3844DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL3844DR-8	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL3845DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL3845DR-8	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL2842DR	SOIC	D	14	2500	367.0	367.0	38.0
TL2842DR-8	SOIC	D	8	2500	340.5	338.1	20.6
TL2843DR	SOIC	D	14	2500	367.0	367.0	38.0
TL2843DR-8	SOIC	D	8	2500	340.5	338.1	20.6
TL2844DR	SOIC	D	14	2500	333.2	345.9	28.6
TL2844DR	SOIC	D	14	2500	367.0	367.0	38.0
TL2844DR-8	SOIC	D	8	2500	340.5	338.1	20.6
TL2845DR	SOIC	D	14	2500	367.0	367.0	38.0
TL2845DR-8	SOIC	D	8	2500	340.5	338.1	20.6
TL3842DR	SOIC	D	14	2500	367.0	367.0	38.0
TL3842DR-8	SOIC	D	8	2500	340.5	338.1	20.6
TL3843DR	SOIC	D	14	2500	367.0	367.0	38.0
TL3843DR-8	SOIC	D	8	2500	340.5	338.1	20.6
TL3844DR	SOIC	D	14	2500	367.0	367.0	38.0
TL3844DR	SOIC	D	14	2500	333.2	345.9	28.6
TL3844DR-8	SOIC	D	8	2500	340.5	338.1	20.6
TL3845DR	SOIC	D	14	2500	367.0	367.0	38.0
TL3845DR-8	SOIC	D	8	2500	340.5	338.1	20.6

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



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